



Micro Commercial Components
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RB441Q

Features

- Low Current, Low V_F
- Glass Sealed Envelope for High Reliability (MSD)
- Silicon Epitaxial Planar Construction

Mechanical Data

- Case: DO-35 glass case
- Polarity: Color band denotes cathode end
- Weight: Approx. 0.13 gram

Maximum Ratings

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	40	V
DC Reverse Voltage	V_R	40	V
Mean Rectifying Current	I_O	0.1	A
Peak Forward Surge Current	I_{FSM}	1	A
Junction Temperature	T_J	125	°C
Storage Temperature	T_{STG}	-40 to 125	°C

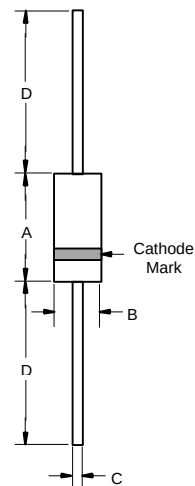
Electrical Characteristics @ 25°C Unless Otherwise Specified

Parameter	Symbol	Typical	Maximum	Unit
Forward Voltage @ $I_F=10mA$	V_{F1}		0.34	V
Forward Voltage @ $I_F=100mA$	V_{F2}	0.45	0.55	V
Reverse Current @ $V_R=40V$	I_R		100	uA
Capacitance Between Terminals @ $V_R=10V$, $f=1MHz$	C_T	6.0		pF

NOTE) ESD sensitive product handling required

0.1 Amp Schottky Barrier Rectifier 40 Volts

DO-35



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	---	.150	---	3.8	
B	---	.079	---	2.00	
C	---	.020	---	.52	
D	1.083	---	27.50	---	

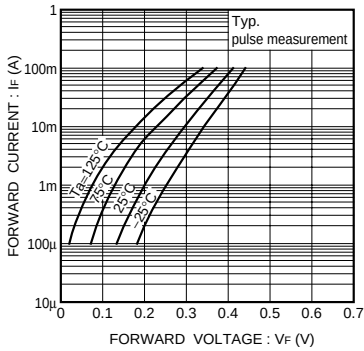


Fig. 1 Forward characteristics

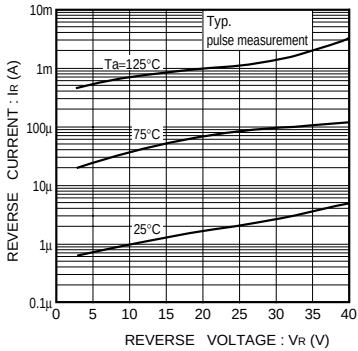


Fig. 2 Reverse characteristics

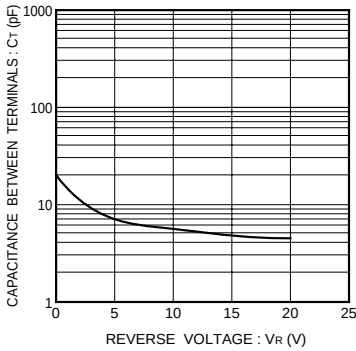


Fig. 3 Capacitance between terminals characteristics

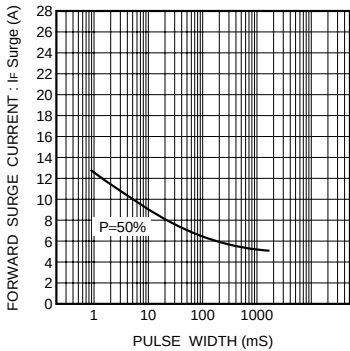


Fig. 4 Forward surge current characteristics

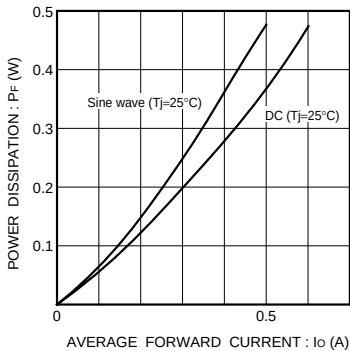


Fig. 5 Mean rectifying current characteristics

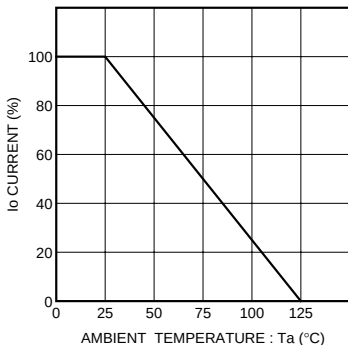


Fig. 6 Derating curve (mounting on glass epoxy PCBs)